## Application Note:

## Designing with Acriche A4

## SAWX4A0X

## Introduction

The Acriche series of devices are designed for ease of implementation and readily connect to AC sources emitting very high flux while minimizing driver requirements.


Acriche products are long-lasting, environmentally friendly semiconductor light sources that can be attached either directly to AC voltages, or as with the A4, to a simple diode bridge (see Fig 6).

Acriche's thermal management exceeds other power LED solutions incorporating state-of-the-art SMD technology, thermal path design, and low thermal resistant materials.
Whether designing a spot light or tiled array, the Acriche A4 is an ideal light source for general purpose illumination applications.

This application note provides assembly and handling information of the A4 series.

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## 1. Component

### 1.1 Description

The ACRICHE A4 emitter is designed to operate off of rectified high voltage AC. The A4 PKG contains a high brightness, high voltage LED chip array on a ceramic substrate that functions as a mechanical support for the chips and connects the LED chip to the anode and cathode of the package. Each A4 emitter contains a zener diode to provide ESD protection. A silicone lens covering the LED chip helps to extract the light and provide environmental protection.


Figure 1. ACRICHE A4 (left) and bottom of A4 (right)

### 1.2 Mechanical Dimensions

As seen in Fig 2 below, the theoretical optical center is located at the center of the A4 package. The anode, cathode and thermal pads are located on the bottom of the package. The cathode mark indicates the cathode pad location. The ceramic substrate electrically isolates the thermal pad or slug from the cathode and anode. Electrical shocks can occur at high voltage, therefore safety considerations should be taken into account by following UL Recommendations.
The A4 has been UL recognized.


Figure 2. ACRICHE A4 mechanical dimensions(mm)

### 1.3 PCB solder pad layout

The ACRICHE A4 emitter should be mounted on a printed circuit board for electrical connections and to give a proper thermal path between the LED package and the heat sink. A temperature check point is recommended to be designed into the solder pad layout which can be used to calculate the junction temperature for thermal degradation and life time calculations. The solder pad should not be designed larger than the recommended size as the part may shift and excess solder paste may form solder balls which can create electrical shorts between internal pads on the


Figure 3. Recommended PCB solder pad layout


Figure 4. Incorrect soldering of the ACRICHE A4 emitter

### 1.4 Junction Temperature

The life time of the ACRICHE A4 emitter is most directly related to the junction temperature, but it is impossible to measure the junction temperature directly without any damage. Tj can be theoretically calculated by using the thermal resistance between the LED junction and the board. The equation for Tj is: $\mathrm{Tj}\left[{ }^{\circ} \mathrm{C}\right]=\mathrm{Tb}\left[{ }^{\circ} \mathrm{C}\right]+\mathrm{R} \Theta \mathrm{j}-\mathrm{b}\left[{ }^{\circ} \mathrm{C} / \mathrm{W}\right] \mathrm{x}$ emitter power[W].

The equation of the emitter power is calculated using the following formula:
$\mathrm{P}[\mathrm{W}]=$ Input Vrms $[\mathrm{V}] \times$ Input $\operatorname{Irms}[\mathrm{A}] \mathrm{X}$ Power Factor $-\operatorname{Irms}^{2}[\mathrm{~A}] \times$ Resistor Value[ $\Omega$.

The rectifier power dissipation is negligible so we are not using this in the calculations, although we do need the Power Factor(PF) for the A4 emitter. It is about 0.89 in the typical drive configuration consisting of only a rectifier and a resistor. (Note: The PF is 1.00 generally in


Figure 5. Thermal modeling of the ACRICHE A4 emitter

### 1.5 Lens handling

Improper handling of the LED packages can damage the silicone lens. Avoid touching the silicone dome of the LED especially with sharp tools. Pick up the LED on the sides of the package. Any physical force to the silicone lens in excess of 3000 gf will permanently and fatally damage the part. The silicone dome is sensitive to dust and debris and can cause an optical output decrease. If dust or debris accumulates on the lens, isopropyl alcohol (IPA) can be used to remove dust from the lens.

## 2. Driver Configurations

### 2.1 Description

The ACRICHE A4 emitter is designed to operate directly off of AC line power(e.g 120Vac, 230Vac) with a rectifier, resistors or optional capacitor(s). This compact circuit can minimize the lighting product size, help simplify thermal design, and increase overall product reliability. It is also an economical solution because you do not need to have all the extra components. Typical low voltage DC circuits require a transformer, regulator and multiple discrete components such as capacitors, inductors, resistors.

### 2.2 Proper resistor selection

Operating the ACRICHE A4 emitter requires a bridge rectifier and resistors at a minimum, since the architecture of the A4 has been modified from the earlier versions of the Acriche family(A2, A3), which did not need a bridge. This architecture has a string of LEDs in one direction only, compared to the previous version which has strings in both directions, thereby not requiring the diode bridge previously. Utilizing the new architecture, we are able to reduce the number of LEDs needed, thereby reducing package size and price.

It is better to use higher than rated power resistors for reliability. The rated power of the resistor should be chosen based on the equation $\operatorname{Irms}(\mathrm{A})^{*} \operatorname{Irms}(\mathrm{~A}) *$ Resistor value(ohms). The normal power rating of a 3216 size resistor is 0.25 W . If the power consumption in one resistor exceeds the rated power of the resistor it is suggested to use multiple resistors in parallel.


Figure 6. Compact drive circuit configuration 100~120Vac

| Input Voltage | Power dissipation | Target Drive Current | VF bins |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | A | B | C | D |
| 100 Vac | 2 W | 20 mA ,rms | $630 \Omega$ | $480 \Omega$ | $330 \Omega$ | $180 \Omega$ |
|  | 3 W | 25 mA , rms | $420 \Omega$ | $270 \Omega$ | $120 \Omega$ | N/A |
|  | 4 W | 30 mA ,rms | $285 \Omega$ | $135 \Omega$ | N/A | N/A |
| 110 Vac | 2 W | 20 mA ,rms | $1060 \Omega$ | $910 \Omega$ | $760 \Omega$ | $610 \Omega$ |
|  | 3 W | $25 \mathrm{~mA}, \mathrm{rms}$ | $765 \Omega$ | $615 \Omega$ | $465 \Omega$ | $315 \Omega$ |
|  | 4 W | 30 mA ,rms | $575 \Omega$ | $425 \Omega$ | $275 \Omega$ | $125 \Omega$ |
| 120 Vac | 2 W | 20 mA ,rms | $1510 \Omega$ | $1360 \Omega$ | $1210 \Omega$ | $1060 \Omega$ |
|  | 3 W | $25 \mathrm{~mA}, \mathrm{rms}$ | $1125 \Omega$ | $975 \Omega$ | $825 \Omega$ | $675 \Omega$ |
|  | 4 W | 30 mA ,rms | $870 \Omega$ | $720 \Omega$ | $570 \Omega$ | $420 \Omega$ |

Table 1. Resistor values in Figure 6. (left)

| Input Voltage | Power dissipation | Target Drive Current | VF bins |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | A | B | C | D |
| 100 Vac | 4 W | 40 mA ,rms | $315 \Omega$ | $240 \Omega$ | $165 \Omega$ | $90 \Omega$ |
|  | 6 W | 50 mA , rms | $210 \Omega$ | $135 \Omega$ | $60 \Omega$ | N/A |
|  | 8 W | 60 mA , rms | $140 \Omega$ | $65 \Omega$ | N/A | N/A |
| 110 Vac | 4 W | 40 mA ,rms | $530 \Omega$ | $455 \Omega$ | $380 \Omega$ | $305 \Omega$ |
|  | 6 W | 50 mA ,rms | $385 \Omega$ | $310 \Omega$ | $235 \Omega$ | $160 \Omega$ |
|  | 8 W | 60 mA ,rms | $285 \Omega$ | $210 \Omega$ | $135 \Omega$ | $60 \Omega$ |
| 120 Vac | 4 W | 40 mA ,rms | $755 \Omega$ | $680 \Omega$ | $605 \Omega$ | $530 \Omega$ |
|  | 6 W | 50 mA ,rms | $565 \Omega$ | $490 \Omega$ | $415 \Omega$ | $340 \Omega$ |
|  | 8 W | $60 \mathrm{~mA}, \mathrm{rms}$ | $435 \Omega$ | $360 \Omega$ | $285 \Omega$ | $210 \Omega$ |

Table 2. Resistor values in Figure 6. (right)

* Notes :
[1] SSC recommends that MS6B (Max input voltage: 420Vrms) would be used as a bridge rectifier.
[2] Applicable Part Numbers are currently SAW04A0A (AW4240-01) and SAW84A0C (AN4240-03)


Figure 7. Standard compact drive circuit configuration 220~240Vac

| Input Voltage | Power dissipation | Target Drive Current | VF bins |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | A | B | C | D |
| 220 Vac | 4 W | 20 mA ,rms | $2200 \Omega$ | $1900 \Omega$ | $1600 \Omega$ | $1300 \Omega$ |
|  | 6 W | 25 mA ,rms | $1570 \Omega$ | $1270 \Omega$ | $970 \Omega$ | $670 \Omega$ |
|  | 8 W | 30 mA , rms | $1180 \Omega$ | $880 \Omega$ | $580 \Omega$ | $280 \Omega$ |
| 230 Vac | 4 W | 20 mA ,rms | $2640 \Omega$ | $2340 \Omega$ | $2040 \Omega$ | $1740 \Omega$ |
|  | 6 W | $25 \mathrm{~mA}, \mathrm{rms}$ | 1930 ת | $1630 \Omega$ | 1330 ת | $1030 \Omega$ |
|  | 8 W | $30 \mathrm{~mA}, \mathrm{rms}$ | $1480 \Omega$ | $1180 \Omega$ | $880 \Omega$ | $580 \Omega$ |
| 240 Vac | 4 W | 20 mA ,rms | $3080 \Omega$ | $2780 \Omega$ | $2480 \Omega$ | $2180 \Omega$ |
|  | 6 W | $25 \mathrm{~mA}, \mathrm{rms}$ | 2290 ת | 1990 ת | 1690 ת | 1390 ת |
|  | 8 W | $30 \mathrm{~mA}, \mathrm{rms}$ | $1780 \Omega$ | $1480 \Omega$ | $1180 \Omega$ | $880 \Omega$ |

Table 3. Resistor values in Figure 7.

### 2.3 Optional Components/Configurations

Acriche A4 can be operated in three additional optional configurations if higher efficiency or less flicker is needed. These optional configurations can lower power factor as seen in Table 13. The three different component configurations consist of a bridge diode, resistor, and capacitor(s).

Optional Configuration \#1 : output resistor + output capcacitor(parallel)
Optional Configuration \#2 : Input capacitor(series) + output resistor
Optional Configuration \#3 : Input capacitor(series) + output capcacitor(parallel) + output resistor


Figure 8. Current waveforms of different circuit configurations

Optional circuit configuration\#1: This adds an output capacitor to the standard circuit. This configuration has no flicker. The current shape through the A4 package is similar to DC current, as seen in Figure 8. Input current and LED current are not the same value. The target drive current indicates LED current through A4 PKG. There is no difference in resistor values between 50 Hz and 60 Hz of frequency.


Figure 9. Optional compact drive circuit configuration\#1

| Input Voltage | Frequency | LED\# | Target Drive Current ( $\mathrm{I}_{\text {led, }}$ not $\mathrm{I}_{\text {in }}$ ) | Cout | Rout for VF bins |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | A | B | C | D |
| 220 Vac | 50Hz/60Hz | 4 ea | 20 mA , rms | 47 uF | $4650 \Omega$ | $4350 \Omega$ | $4050 \Omega$ | $3750 \Omega$ |
|  |  |  | 30 mA , rms | 47 uF | $2750 \Omega$ | $2450 \Omega$ | $2150 \Omega$ | $1850 \Omega$ |
|  |  |  | $40 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | $1850 \Omega$ | $1550 \Omega$ | $1250 \Omega$ | $950 \Omega$ |
|  |  | 5 ea | 20 mA , rms | 47 uF | $1960 \Omega$ | $1580 \Omega$ | $1210 \Omega$ | $830 \Omega$ |
| 230 Vac | 50Hz/60Hz | 4 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | 5350 ת | $5050 \Omega$ | $4750 \Omega$ | $4450 \Omega$ |
|  |  |  | 30 mA , rms | 47 uF | $3250 \Omega$ | 2950 ת | $2650 \Omega$ | 2350 ת |
|  |  |  | $40 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | $2200 \Omega$ | $1900 \Omega$ | $1600 \Omega$ | $1300 \Omega$ |
|  |  | 5 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | $2670 \Omega$ | 2290 ת | $1920 \Omega$ | $1540 \Omega$ |
|  |  |  | $30 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | $1370 \Omega$ | $1000 \Omega$ | $620 \Omega$ | $250 \Omega$ |
| 240 Vac | $50 \mathrm{~Hz} / 60 \mathrm{~Hz}$ | 4 ea | 20 mA ,rms | 47 uF | $6050 \Omega$ | $5750 \Omega$ | $5450 \Omega$ | $5150 \Omega$ |
|  |  |  | 30 mA ,rms | 47 uF | $3700 \Omega$ | $3400 \Omega$ | $3100 \Omega$ | $2800 \Omega$ |
|  |  |  | $40 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | $2550 \Omega$ | $2250 \Omega$ | $1950 \Omega$ | $1650 \Omega$ |
|  |  | 5 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | 3380 ת | $3000 \Omega$ | $2630 \Omega$ | $2250 \Omega$ |
|  |  |  | $30 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | $1850 \Omega$ | $1470 \Omega$ | $1100 \Omega$ | $720 \Omega$ |
| 100 Vac | 50Hz/60Hz | 2 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | 100 uF | $1580 \Omega$ | $1430 \Omega$ | $1280 \Omega$ | $1130 \Omega$ |
|  |  |  | $30 \mathrm{~mA}, \mathrm{rms}$ | 100 uF | $890 \Omega$ | $740 \Omega$ | $590 \Omega$ | $440 \Omega$ |
| 110 Vac | 50Hz/60Hz | 2 ea | 20 mA ,rms | 100 uF | $2290 \Omega$ | $2140 \Omega$ | $1990 \Omega$ | $1840 \Omega$ |
|  |  |  | $30 \mathrm{~mA}, \mathrm{rms}$ | 100 uF | 1360 ת | $1210 \Omega$ | $1060 \Omega$ | $910 \Omega$ |
|  |  |  | 40 mA ,rms | 100 uF | $910 \Omega$ | $760 \Omega$ | $610 \Omega$ | $460 \Omega$ |
| 120 Vac | 50Hz/60Hz | 2 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | 100 uF | 2990 ת | 2840 ת | $2690 \Omega$ | $2540 \Omega$ |
|  |  |  | 30 mA ,rms | 100 uF | $1830 \Omega$ | $1680 \Omega$ | $1530 \Omega$ | $1380 \Omega$ |
|  |  |  | 40 mA ,rms | 100 uF | $1260 \Omega$ | $1110 \Omega$ | $960 \Omega$ | $810 \Omega$ |

Table 4. Resistor and capacitor values in Figure 9

Optional circuit configuration\#2: This adds an input capacitor to the standard circuit. This Configuration has the same current shape through the A4 package as the standard AC drive (as seen in Figure 8), but since it can only drive one LED string it is very suitable for compact designs like a candle lamp. Additionally the circuit efficiency is very high(see table 13). You can also improve efficiency a little by eliminating the output resistor(Rout), but SSC recommends using Rout for surge immunity.


Figure 10. Optional compact drive circuit configuration\#2

| Input Voltage | Frequency | LED\# | Target Drive Current$\left(\mathrm{I}_{\text {LED }}=\mathrm{I}_{\text {in }}\right)$ | Rout | Cin for VF bins |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | A | B | C | D |
| 220 Vac | 50 Hz | 4 ea | 20 mA , rms | $100 \Omega$ | 560 nF | 590 nF | 640 nF | 700 nF |
|  |  |  | 30 mA , rms | $100 \Omega$ | 920 nF | 1060 nF | 1320 nF | N/A |
|  |  | 3 ea | 20 mA ,rms | $100 \Omega$ | 410 nF | 420 nF | 420 nF | 430 nF |
|  |  |  | 30 mA ,rms | $100 \Omega$ | 630 nF | 650 nF | 680 nF | 710 nF |
|  |  |  | 40 mA ,rms | $100 \Omega$ | 870 nF | 920 nF | 980 nF | 1060 nF |
|  |  | 2 ea | 20 mA ,rms | $100 \Omega$ | 350 nF | 350 nF | 350 nF | 350 nF |
|  |  |  | 30 mA , rms | $100 \Omega$ | 530 nF | 530 nF | 530 nF | 540 nF |
|  |  |  | 40 mA ,rms | $100 \Omega$ | 720 nF | 720 nF | 720 nF | 730 nF |
|  |  | 1 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | $100 \Omega$ | 310 nF | 310 nF | 310 nF | 310 nF |
|  |  |  | 30 mA ,rms | $100 \Omega$ | 460 nF | 460 nF | 460 nF | 460 nF |
|  |  |  | 40 mA ,rms | $100 \Omega$ | 620 nF | 620 nF | 620 nF | 620 nF |
|  | 60 Hz | 4 ea | 20 mA ,rms | $100 \Omega$ | 470 nF | 490 nF | 530 nF | 580 nF |
|  |  |  | 30 mA ,rms | $100 \Omega$ | 770 nF | 880 nF | 1100 nF | N/A |
|  |  | 3 ea | 20 mA ,rms | $100 \Omega$ | 340 nF | 350 nF | 350 nF | 360 nF |
|  |  |  | $30 \mathrm{~mA}, \mathrm{rms}$ | $100 \Omega$ | 530 nF | 550 nF | 570 nF | 590 nF |
|  |  |  | 40 mA ,rms | $100 \Omega$ | 730 nF | 760 nF | 810 nF | 880 nF |
|  |  | 2 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | $100 \Omega$ | 290 nF | 290 nF | 290 nF | 290 nF |
|  |  |  | $30 \mathrm{~mA}, \mathrm{rms}$ | $100 \Omega$ | 440 nF | 440 nF | 440 nF | 450 nF |
|  |  |  | 40 mA ,rms | $100 \Omega$ | 600 nF | 600 nF | 600 nF | 610 nF |
|  |  | 1 ea | 20 mA ,rms | $100 \Omega$ | 260 nF | 260 nF | 260 nF | 260 nF |
|  |  |  | $30 \mathrm{~mA}, \mathrm{rms}$ | $100 \Omega$ | 380 nF | 380 nF | 390 nF | 390 nF |
|  |  |  | 40 mA ,rms | $100 \Omega$ | 510 nF | 510 nF | 520 nF | 520 nF |

Table 5. Resistor and capacitor values in Figure 10 (220Vac)
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| Input Voltage | Frequency | LED\# | Target Drive Current ( $\mathrm{I}_{\text {LED }}=\mathrm{I}_{\text {in }}$ ) | Rout | Cin for VF bins |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | A | B | C | D |
| 230 Vac | 50 Hz | 4 ea | 20 mA , rms | $100 \Omega$ | 500 nF | 520 nF | 550 nF | 590 nF |
|  |  |  | 30 mA , rms | $100 \Omega$ | 800 nF | 890 nF | 1020 nF | 1280 nF |
|  |  |  | 40 mA ,rms | $100 \Omega$ | 1180 nF | 1430 nF | N/A | N/A |
|  |  | 3 ea | 20 mA , rms | $100 \Omega$ | 380 nF | 390 nF | 390 nF | 400 nF |
|  |  |  | 30 mA ,rms | $100 \Omega$ | 590 nF | 600 nF | 620 nF | 640 nF |
|  |  |  | 40 mA ,rms | $100 \Omega$ | 800 nF | 840 nF | 880 nF | 940 nF |
|  |  | 2 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | $100 \Omega$ | 330 nF | 330 nF | 330 nF | 330 nF |
|  |  |  | 30 mA ,rms | $100 \Omega$ | 500 nF | 500 nF | 500 nF | 500 nF |
|  |  |  | 40 mA ,rms | $100 \Omega$ | 680 nF | 680 nF | 680 nF | 690 nF |
|  |  | 1 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | $100 \Omega$ | 290 nF | 290 nF | 290 nF | 290 nF |
|  |  |  | 30 mA ,rms | $100 \Omega$ | 440 nF | 440 nF | 440 nF | 440 nF |
|  |  |  | 40 mA ,rms | $100 \Omega$ | 590 nF | 590 nF | 590 nF | 590 nF |
|  | 60 Hz | 4 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | $100 \Omega$ | 420 nF | 430 nF | 460 nF | 490 nF |
|  |  |  | $30 \mathrm{~mA}, \mathrm{rms}$ | $100 \Omega$ | 670 nF | 740 nF | 850 nF | 1060 nF |
|  |  |  | 40 mA ,rms | $100 \Omega$ | 980 nF | 1190 nF | N/A | N/A |
|  |  | 3 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | $100 \Omega$ | 320 nF | 320 nF | 330 nF | 330 nF |
|  |  |  | 30 mA ,rms | $100 \Omega$ | 490 nF | 500 nF | 520 nF | 540 nF |
|  |  |  | 40 mA ,rms | $100 \Omega$ | 670 nF | 700 nF | 730 nF | 780 nF |
|  |  | 2 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | $100 \Omega$ | 270 nF | 270 nF | 270 nF | 270 nF |
|  |  |  | 30 mA ,rms | $100 \Omega$ | 420 nF | 420 nF | 420 nF | 420 nF |
|  |  |  | $40 \mathrm{~mA}, \mathrm{rms}$ | $100 \Omega$ | 560 nF | 560 nF | 560 nF | 570 nF |
|  |  | 1 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | $100 \Omega$ | 240 nF | 240 nF | 240 nF | 240 nF |
|  |  |  | 30 mA ,rms | $100 \Omega$ | 370 nF | 370 nF | 370 nF | 370 nF |
|  |  |  | $40 \mathrm{~mA}, \mathrm{rms}$ | $100 \Omega$ | 490 nF | 490 nF | 490 nF | 490 nF |

Table 6. Resistor and capacitor values in Figure 10 (230Vac)
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| Input Voltage | Frequency | LED\# | Target Drive Current ( $\mathrm{I}_{\text {LED }}=\mathrm{I}_{\text {in }}$ ) | Rout | Cin for VF bins |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | A | B | C | D |
| 240 Vac | 50 Hz | 4 ea | 20 mA , rms | $100 \Omega$ | 450 nF | 470 nF | 490 nF | 510 nF |
|  |  |  | $30 \mathrm{~mA}, \mathrm{rms}$ | $100 \Omega$ | 720 nF | 770 nF | 860 nF | 990 nF |
|  |  |  | 40 mA ,rms | $100 \Omega$ | 1030 nF | 1180 nF | 1500 nF | N/A |
|  |  | 3 ea | 20 mA , rms | $100 \Omega$ | 360 nF | 360 nF | 370 nF | 370 nF |
|  |  |  | 30 mA ,rms | $100 \Omega$ | 550 nF | 560 nF | 570 nF | 590 nF |
|  |  |  | 40 mA ,rms | $100 \Omega$ | 750 nF | 770 nF | 810 nF | 850 nF |
|  |  | 2 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | $100 \Omega$ | 310 nF | 310 nF | 310 nF | 310 nF |
|  |  |  | 30 mA ,rms | $100 \Omega$ | 470 nF | 470 nF | 470 nF | 480 nF |
|  |  |  | 40 mA ,rms | $100 \Omega$ | 640 nF | 640 nF | 640 nF | 650 nF |
|  |  | 1 ea | 20 mA ,rms | $100 \Omega$ | 280 nF | 280 nF | 280 nF | 280 nF |
|  |  |  | 30 mA ,rms | $100 \Omega$ | 420 nF | 420 nF | 420 nF | 420 nF |
|  |  |  | 40 mA ,rms | $100 \Omega$ | 560 nF | 560 nF | 560 nF | 560 nF |
|  | 60 Hz | 4 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | $100 \Omega$ | 380 nF | 390 nF | 410 nF | 430 nF |
|  |  |  | $30 \mathrm{~mA}, \mathrm{rms}$ | $100 \Omega$ | 600 nF | 640 nF | 710 nF | 820 nF |
|  |  |  | 40 mA ,rms | $100 \Omega$ | 860 nF | 990 nF | 1250 nF | N/A |
|  |  | 3 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | $100 \Omega$ | 300 nF | 300 nF | 300 nF | 310 nF |
|  |  |  | 30 mA ,rms | $100 \Omega$ | 460 nF | 470 nF | 480 nF | 490 nF |
|  |  |  | $40 \mathrm{~mA}, \mathrm{rms}$ | $100 \Omega$ | 620 nF | 640 nF | 670 nF | 710 nF |
|  |  | 2 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | $100 \Omega$ | 260 nF | 260 nF | 260 nF | 260 nF |
|  |  |  | 30 mA ,rms | $100 \Omega$ | 390 nF | 390 nF | 390 nF | 400 nF |
|  |  |  | $40 \mathrm{~mA}, \mathrm{rms}$ | $100 \Omega$ | 530 nF | 530 nF | 530 nF | 540 nF |
|  |  | 1 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | $100 \Omega$ | 230 nF | 230 nF | 230 nF | 230 nF |
|  |  |  | 30 mA ,rms | $100 \Omega$ | 350 nF | 350 nF | 350 nF | 350 nF |
|  |  |  | $40 \mathrm{~mA}, \mathrm{rms}$ | $100 \Omega$ | 470 nF | 470 nF | 470 nF | 470 nF |

Table 7. Resistor and capacitor values in Figure 10 (240Vac)

| Input Voltage | Frequency | LED\# | Target Drive Current $\left(\mathrm{I}_{\text {LED }}=\mathrm{I}_{\text {in }}\right)$ | Rout | Cin for VF bins |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | A | B | C | D |
| 100Vac | 50 Hz | 2 ea | 20 mA , rms | $100 \Omega$ | 1600 nF | 1850 nF | 2340 nF | N/A |
|  |  | 1 ea | 20 mA , rms | $100 \Omega$ | 780 nF | 790 nF | 800 nF | 800 nF |
|  |  |  | 30 mA , rms | $100 \Omega$ | 1200 nF | 1210 nF | 1230 nF | 1250 nF |
|  |  |  | 40 mA ,rms | $100 \Omega$ | 1630 nF | 1660 nF | 1700 nF | 1740 nF |
|  | 60 Hz | 2 ea | 20 mA , rms | $100 \Omega$ | 1340 nF | 1550 nF | 1950 nF | N/A |
|  |  | 1 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | $100 \Omega$ | 650 nF | 660 nF | 660 nF | 670 nF |
|  |  |  | 30 mA , rms | $100 \Omega$ | 1000 nF | 1010 nF | 1020 nF | 1040 nF |
|  |  |  | 40 mA , rms | $100 \Omega$ | 1350 nF | 1380 nF | 1410 nF | 1450 nF |
| 110 Vac | 50 Hz | 2 ea | 20 mA ,rms | $100 \Omega$ | 1150 nF | 1230 nF | 1330 nF | 1490 nF |
|  |  |  | $30 \mathrm{~mA}, \mathrm{rms}$ | $100 \Omega$ | 1950 nF | 2290 nF | 3100 nF | N/A |
|  |  | 1 ea | 20 mA ,rms | $100 \Omega$ | 690 nF | 690 nF | 700 nF | 700 nF |
|  |  |  | 30 mA , rms | $100 \Omega$ | 1050 nF | 1060 nF | 1070 nF | 1080 nF |
|  |  |  | $40 \mathrm{~mA}, \mathrm{rms}$ | $100 \Omega$ | 1420 nF | 1440 nF | 1470 nF | 1500 nF |
|  | 60 Hz | 2 ea | 20 mA , rms | $100 \Omega$ | 960 nF | 1020 nF | 1110 nF | 1250 nF |
|  |  |  | 30 mA , rms | $100 \Omega$ | 1620 nF | 1910 nF | 2550 nF | N/A |
|  |  | 1 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | $100 \Omega$ | 580 nF | 580 nF | 580 nF | 590 nF |
|  |  |  | 30 mA , rms | $100 \Omega$ | 870 nF | 880 nF | 890 nF | 900 nF |
|  |  |  | 40 mA ,rms | $100 \Omega$ | 1180 nF | 1200 nF | 1220 nF | 1250 nF |
| 120 Vac | 50 Hz | 2 ea | 20 mA ,rms | $100 \Omega$ | 920 nF | 950 nF | 1000 nF | 1060 nF |
|  |  |  | $30 \mathrm{~mA}, \mathrm{rms}$ | $100 \Omega$ | 1480 nF | 1620 nF | 1810 nF | 2150 nF |
|  |  |  | $40 \mathrm{~mA}, \mathrm{rms}$ | $100 \Omega$ | 2170 nF | 2570 nF | 3500 nF | N/A |
|  |  | 1 ea | 20 mA ,rms | $100 \Omega$ | 620 nF | 620 nF | 620 nF | 630 nF |
|  |  |  | 30 mA ,rms | $100 \Omega$ | 940 nF | 940 nF | 950 nF | 960 nF |
|  |  |  | $40 \mathrm{~mA}, \mathrm{rms}$ | $100 \Omega$ | 1260 nF | 1280 nF | 1300 nF | 1320 nF |
|  | 60 Hz | 2 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | $100 \Omega$ | 760 nF | 800 nF | 930 nF | 880 nF |
|  |  |  | 30 mA ,rms | $100 \Omega$ | 1240 nF | 1350 nF | 1510 nF | 1800 nF |
|  |  |  | $40 \mathrm{~mA}, \mathrm{rms}$ | $100 \Omega$ | 1810 nF | 2140 nF | 2900 nF | N/A |
|  |  | 1 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | $100 \Omega$ | 510 nF | 520 nF | 520 nF | 520 nF |
|  |  |  | 30 mA ,rms | $100 \Omega$ | 780 nF | 790 nF | 790 nF | 800 nF |
|  |  |  | $40 \mathrm{~mA}, \mathrm{rms}$ | $100 \Omega$ | 1050 nF | 1070 nF | 1080 nF | 1100 nF |

Table 8. Resistor and capacitor values in Figure 10 (100~120 Vac)

We can also see based on Figure 10, the peak currents and waveforms are different based on number of LEDs in the circuit. The more LEDs in the circuit the higher the peak current in identical currents(i.e. 20 mA rms ). This translates into lower luminous output because of droop, but we will see higher power factors with more LEDs. Flicker can be more prominent with a higher number of LEDs as you can see there is more off time with more LEDs.


Figure 11. LED current shape for 1-4 LEDs. Input Voltage is $\mathbf{2 3 0 V a c} @ \mathbf{5 0 H z}$ and target LED current is $\mathbf{2 0 m A}$, rms.

Figure 12 shows LED current vs input voltage variation on A4 with 1-4 emitters. When quantities of LEDs decrease, the current variation is less.


Figure 12. LED current variation at input voltage range (230Vac $\pm \mathbf{2 0 \%}$ ) in Figure10.
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Optional circuit configuration\#3: This adds an input capacitor and output capacitor to the standard circuit. This configuration has no flicker and the current shape through the A4 package is similar to DC current, as seen in Figure 8. This means we get a combination of configurations \#1 \& 2, higher efficiency and no flicker issues.


Figure 13. Optional compact drive circuit configuration\#3

| Input Voltage | Frequency | LED\# | Target Drive Current ( $\mathrm{I}_{\text {led, }}$ not $\mathrm{I}_{\mathrm{in}}$ ) | Cout | Rout | Cin for VF bins |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  | A | B | C | D |
| 220 Vac | 50 Hz | 4 ea | 20 mA , rms | 47 uF | $390 \Omega$ | 1160 nF | 1250 nF | 1350 nF | 1470 nF |
|  |  |  | $30 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | $390 \Omega$ | 2060 nF | 2350 nF | 2760 nF | N/A |
|  |  | 3 ea | 20 mA , rms | 47 uF | $300 \Omega$ | 700 nF | 730 nF | 760 nF | 780 nF |
|  |  |  | 30 mA ,rms | 47 uF | $300 \Omega$ | 1140 nF | 1200 nF | 1270 nF | 1350 nF |
|  |  |  | $40 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | $300 \Omega$ | 1630 nF | 1760 nF | 1920 nF | 2100 nF |
|  |  | 2 ea | 20 mA , rms | 47 uF | $200 \Omega$ | 510 nF | 510 nF | 520 nF | 530 nF |
|  |  |  | 30 mA , rms | 47 uF | $200 \Omega$ | 780 nF | 800 nF | 820 nF | 840 nF |
|  |  |  | $40 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | $200 \Omega$ | 1080 nF | 1120 nF | 1160 nF | 1200 nF |
|  |  | 1 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | $100 \Omega$ | 390 nF | 400 nF | 400 nF | 400 nF |
|  |  |  | 30 mA ,rms | 47 uF | $100 \Omega$ | 600 nF | 600 nF | 610 nF | 610 nF |
|  |  |  | $40 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | $100 \Omega$ | 800 nF | 820 nF | 830 nF | 840 nF |
|  | 60 Hz | 4 ea | 20 mA , rms | 47 uF | $390 \Omega$ | 960 nF | 1040 nF | 1120 nF | 1220 nF |
|  |  |  | 30 mA , rms | 47 uF | $390 \Omega$ | 1710 nF | 1960 nF | 2280 nF | N/A |
|  |  | 3 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | $300 \Omega$ | 590 nF | 610 nF | 630 nF | 650 nF |
|  |  |  | $30 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | $300 \Omega$ | 950 nF | 1000 nF | 1060 nF | 1120 nF |
|  |  |  | $40 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | $300 \Omega$ | 1360 nF | 1470 nF | 1600 nF | 1750 nF |
|  |  | 2 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | $200 \Omega$ | 420 nF | 430 nF | 430 nF | 440 nF |
|  |  |  | 30 mA ,rms | 47 uF | $200 \Omega$ | 650 nF | 670 nF | 690 nF | 700 nF |
|  |  |  | 40 mA ,rms | 47 uF | $200 \Omega$ | 900 nF | 930 nF | 960 nF | 1000 nF |
|  |  | 1 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | $100 \Omega$ | 330 nF | 330 nF | 330 nF | 330 nF |
|  |  |  | 30 mA ,rms | 47 uF | $100 \Omega$ | 500 nF | 500 nF | 510 nF | 510 nF |
|  |  |  | $40 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | $100 \Omega$ | 670 nF | 680 nF | 690 nF | 700 nF |

Table 9. Resistor and capacitor values in Figure 12 (220Vac)

| Input Voltage | Frequency | LED\# | Target Drive Current ( $\mathrm{I}_{\text {led }}$ not $\mathrm{I}_{\text {in }}$ ) | Cout | Rout | Cin for VF bins |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  | A | B | C | D |
| 230 Vac | 50 Hz | 4 ea | 20 mA , rms | 47 uF | $390 \Omega$ | 990 nF | 1060 nF | 1130 nF | 1210 nF |
|  |  |  | $30 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | $390 \Omega$ | 1720 nF | 1930 nF | 2180 nF | 2520 nF |
|  |  | 3 ea | 20 mA , rms | 47 uF | $300 \Omega$ | 640 nF | 660 nF | 680 nF | 710 nF |
|  |  |  | 30 mA , rms | 47 uF | $300 \Omega$ | 1030 nF | 1080 nF | 1130 nF | 1190 nF |
|  |  |  | 40 mA , rms | 47 uF | $300 \Omega$ | 1460 nF | 1570 nF | 1690 nF | 1830 nF |
|  |  | 2 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | $200 \Omega$ | 470 nF | 480 nF | 490 nF | 490 nF |
|  |  |  | 30 mA ,rms | 47 uF | $200 \Omega$ | 730 nF | 750 nF | 760 nF | 780 nF |
|  |  |  | 40 mA ,rms | 47 uF | $200 \Omega$ | 1000 nF | 1040 nF | 1070 nF | 1100 nF |
|  |  | 1 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | $100 \Omega$ | 370 nF | 370 nF | 380 nF | 380 nF |
|  |  |  | 30 mA ,rms | 47 uF | $100 \Omega$ | 560 nF | 570 nF | 570 nF | 580 nF |
|  |  |  | 40 mA ,rms | 47 uF | $100 \Omega$ | 760 nF | 770 nF | 780 nF | 790 nF |
|  | 60 Hz | 4 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | $390 \Omega$ | 830 nF | 880 nF | 940 nF | 1010 nF |
|  |  |  | 30 mA ,rms | 47 uF | $390 \Omega$ | 1430 nF | 1600 nF | 1810 nF | 2100 nF |
|  |  | 3 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | $300 \Omega$ | 530 nF | 550 nF | 570 nF | 590 nF |
|  |  |  | 30 mA ,rms | 47 uF | $300 \Omega$ | 850 nF | 900 nF | 940 nF | 990 nF |
|  |  |  | $40 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | $300 \Omega$ | 1220 nF | 1300 nF | 1400 nF | 1520 nF |
|  |  | 2 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | $200 \Omega$ | 390 nF | 400 nF | 400 nF | 410 nF |
|  |  |  | 30 mA ,rms | 47 uF | $200 \Omega$ | 610 nF | 620 nF | 630 nF | 650 nF |
|  |  |  | $40 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | $200 \Omega$ | 840 nF | 860 nF | 890 nF | 920 nF |
|  |  | 1 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | $100 \Omega$ | 310 nF | 310 nF | 310 nF | 310 nF |
|  |  |  | 30 mA ,rms | 47 uF | $100 \Omega$ | 470 nF | 480 nF | 480 nF | 480 nF |
|  |  |  | $40 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | $100 \Omega$ | 630 nF | 640 nF | 650 nF | 660 nF |

Table 10. Resistor and capacitor values in Figure 12 (230Vac)

| Input Voltage | Frequency | LED\# | Target Drive Current ( $\mathrm{I}_{\text {Led, }}$ not $\mathrm{I}_{\mathrm{in}}$ ) | Cout | Rout | Cin for VF bins |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  | A | B | C | D |
| 240 Vac | 50 Hz | 4 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | $390 \Omega$ | 870 nF | 920 nF | 970 nF | 1030 nF |
|  |  |  | $30 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | $390 \Omega$ | 1480 nF | 1630 nF | 1810 nF | 2030 nF |
|  |  | 3 ea | 20 mA , rms | 47 uF | $300 \Omega$ | 590 nF | 600 nF | 620 nF | 640 nF |
|  |  |  | 30 mA , rms | 47 uF | $300 \Omega$ | 940 nF | 980 nF | 1020 nF | 1070 nF |
|  |  |  | 40 mA ,rms | 47 uF | $300 \Omega$ | 1330 nF | 1410 nF | 1500 nF | 1620 nF |
|  |  | 2 ea | 20 mA , rms | 47 uF | $200 \Omega$ | 440 nF | 450 nF | 450 nF | 460 nF |
|  |  |  | 30 mA ,rms | 47 uF | $200 \Omega$ | 680 nF | 700 nF | 710 nF | 720 nF |
|  |  |  | 40 mA , rms | 47 uF | $200 \Omega$ | 940 nF | 960 nF | 990 nF | 1020 nF |
|  |  | 1 ea | 20 mA ,rms | 47 uF | $100 \Omega$ | 350 nF | 350 nF | 360 nF | 360 nF |
|  |  |  | $30 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | $100 \Omega$ | 530 nF | 540 nF | 550 nF | 550 nF |
|  |  |  | 40 mA ,rms | 47 uF | $100 \Omega$ | 720 nF | 730 nF | 740 nF | 750 nF |
|  | 60 Hz | 4 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | $390 \Omega$ | 730 nF | 770 nF | 810 nF | 860 nF |
|  |  |  | 30 mA ,rms | 47 uF | $390 \Omega$ | 1230 nF | 1350 nF | 1500 nF | 1680 nF |
|  |  |  | $40 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | $390 \Omega$ | 1880 nF | 2170 nF | 2600 nF | 3200 nF |
|  |  | 3 ea | 20 mA ,rms | 47 uF | $300 \Omega$ | 490 nF | 500 nF | 520 nF | 540 nF |
|  |  |  | $30 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | $300 \Omega$ | 780 nF | 810 nF | 850 nF | 890 nF |
|  |  |  | $40 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | $300 \Omega$ | 1100 nF | 1170 nF | 1250 nF | 1350 nF |
|  |  | 2 ea | 20 mA ,rms | 47 uF | $200 \Omega$ | 370 nF | 370 nF | 380 nF | 380 nF |
|  |  |  | $30 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | $200 \Omega$ | 570 nF | 580 nF | 590 nF | 600 nF |
|  |  |  | $40 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | $200 \Omega$ | 780 nF | 800 nF | 830 nF | 850 nF |
|  |  | 1 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | $100 \Omega$ | 300 nF | 300 nF | 300 nF | 300 nF |
|  |  |  | 30 mA ,rms | 47 uF | $100 \Omega$ | 450 nF | 450 nF | 460 nF | 460 nF |
|  |  |  | $40 \mathrm{~mA}, \mathrm{rms}$ | 47 uF | $100 \Omega$ | 600 nF | 610 nF | 620 nF | 620 nF |

Table 11. Resistor and capacitor values in Figure 12 (240Vac)

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| Input Voltage | Frequency | LED\# | Target Drive Current ( $\mathrm{I}_{\text {Led, }}$ not $\mathrm{I}_{\mathrm{in}}$ ) | Cout | Rout | Cin for VF bins |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  | A | B | C | D |
| 100 Vac | 50 Hz | 1 ea | 20 mA , rms | 100 uF | $100 \Omega$ | 1180 nF | 1210 nF | 1230 nF | 1250 nF |
|  |  |  | 30 mA , rms | 100 uF | $100 \Omega$ | 1850 nF | 1910 nF | 1960 nF | 2020 nF |
|  |  |  | $40 \mathrm{~mA}, \mathrm{rms}$ | 100 uF | $100 \Omega$ | 2570 nF | 2680 nF | 2790 nF | 2910 nF |
|  | 60 Hz | 1 ea | 20 mA , rms | 100 uF | $100 \Omega$ | 990 nF | 1010 nF | 1030 nF | 1050 nF |
|  |  |  | 30 mA , rms | 100 uF | $100 \Omega$ | 1530 nF | 1590 nF | 1640 nF | 1690 nF |
|  |  |  | 40 mA , rms | 100 uF | $100 \Omega$ | 2140 nF | 2230 nF | 2320 nF | 2420 nF |
| 110 Vac | 50 Hz | 2 ea | 20 mA , rms | 100 uF | $200 \Omega$ | 2360 nF | 2550 nF | 2770 nF | 3000 nF |
|  |  | 1 ea | 20 mA , rms | 100 uF | $100 \Omega$ | 1010 nF | 1030 nF | 1050 nF | 1070 nF |
|  |  |  | 30 mA , rms | 100 uF | $100 \Omega$ | 1580 nF | 1620 nF | 1660 nF | 1700 nF |
|  |  |  | 40 mA , rms | 100 uF | $100 \Omega$ | 2170 nF | 2250 nF | 2330 nF | 2410 nF |
|  | 60 Hz | 2 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | 100 uF | $200 \Omega$ | 1970 nF | 2120 nF | 2300 nF | 2500 nF |
|  |  | 1 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | 100 uF | $100 \Omega$ | 850 nF | 860 nF | 870 nF | 890 nF |
|  |  |  | 30 mA ,rms | 100 uF | $100 \Omega$ | 1310 nF | 1350 nF | 1380 nF | 1410 nF |
|  |  |  | $40 \mathrm{~mA}, \mathrm{rms}$ | 100 uF | $100 \Omega$ | 1810 nF | 1870 nF | 1940 nF | 2010 nF |
| 120 Vac | 50 Hz | 2 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | 100 uF | $200 \Omega$ | 1780 nF | 1890 nF | 2010 nF | 2100 nF |
|  |  | 1 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | 100 uF | $100 \Omega$ | 890 nF | 900 nF | 910 nF | 920 nF |
|  |  |  | $30 \mathrm{~mA}, \mathrm{rms}$ | 100 uF | $100 \Omega$ | 1370 nF | 1400 nF | 1430 nF | 1460 nF |
|  |  |  | 40 mA ,rms | 100 uF | $100 \Omega$ | 1880 nF | 1940 nF | 2000 nF | 2060 nF |
|  | 60 Hz | 2 ea | 20 mA ,rms | 100 uF | $200 \Omega$ | 1480 nF | 1570 nF | 1640 nF | 1750 nF |
|  |  | 1 ea | $20 \mathrm{~mA}, \mathrm{rms}$ | 100 uF | $100 \Omega$ | 740 nF | 750 nF | 760 nF | 770 nF |
|  |  |  | 30 mA ,rms | 100 uF | $100 \Omega$ | 1140 nF | 1170 nF | 1190 nF | 1220 nF |
|  |  |  | $40 \mathrm{~mA}, \mathrm{rms}$ | 100 uF | $100 \Omega$ | 1570 nF | 1610 nF | 1660 nF | 1710 nF |

Table 12. Resistor and capacitor values in Figure 12 (100~120Vac)

### 2.4 Circuit configuration performance

The ACRICHE A4 emitter can be operated in diverse configurations. Configuration \#1 has no flicker, but has lower power factor and lower efficiency. On the contrary using Configuration \#2, there are characteristics of high efficiency, higher power factor. Lastly, configuration \#3 has the merit from configuration\#1 \& 2. It has high efficiency, no flicker, but power factor is a little low.

Table 13 shows detail circuit charateristic of four configurations that are operated in $230 \mathrm{Vac} / 50 \mathrm{~Hz}$.

|  | Standard AC Drive | Optional Configuration \#1 | Optional Configuration \#2 | Optional Configuration \#3 |
| :---: | :---: | :---: | :---: | :---: |
| LED \# | 4 ea | 4 ea | 4 ea | 4 ea |
| LED VF rank | C | C | C | C |
| Vin | 230 Vac | 230 Vac | 230 Vac | 230 Vac |
| Frequency | 50 Hz | 50 Hz | 50 Hz | 50 Hz |
| Rout | $2040 \Omega$ | $4750 \Omega$ | $100 \Omega$ | 390 ת |
| Cin | N/A | N/A | 550 nF | 1130 nF |
| Cout | N/A | 47 uF | N/A | 47 uF |
| LED current | $20 \mathrm{~mA}, \mathrm{rms}$ | 20 mA ,rms | 20 mA ,rms | 20 mA ,rms |
| Input current | 20 mA ,rms | $100 \mathrm{~mA}, \mathrm{rms}$ | $20 \mathrm{~mA}, \mathrm{rms}$ | $40 \mathrm{~mA}, \mathrm{rms}$ |
| $P_{\text {in }}$ | 4.16 W | 6.52 W | 3.23 W | 4.71 W |
| $P_{\text {led }}$ | 3.33 W | 4.54 W | 3.17 W | 4.53 W |
| Effciency $\left(\mathrm{P}_{\text {led }} / \mathrm{P}_{\text {in }}\right)$ | 80.15\% | 69.56\% | 98.19\% | 96.23\% |
| Noticeable flicker | 100 Hz | no | 100 Hz | no |
| PF | 0.90 | 0.28 | 0.70 | 0.51 |

Table 13. Circuit characteristic of four configurations with input $\mathbf{2 3 0 V a c} / \mathbf{5 0 H z}$


Figure 14. Four circuit configurations

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### 2.5 Relative light output between AC and DC

The ACRICHE A4 emitter is binned at rectified AC 20 mA , rms, not at constant current 20 mA .
Figure 15 shows relative luminous flux vs current of an AC circuit and a DC circuit. Relative flux results are normalized luminous flux at AC 20 mA, rms. The AC drive current can simply be changed by modifying the resistor value in the circuit.
Optional circuit configurations 1 and 3 are similar to driving at a constant current, therefore they will have similar luminous flux characteristics.


Figure 15. Relative luminous flux between AC and DC driving.

### 2.6 Vf bin combination

If we can combine multiple Vf bins, we can allow for more part acceptability in the system application, thereby allowing a wider availability of parts. The ACRICHE A4 emitter can be operated by mixing VF bins. The left picture of Figure 16 is an example of a series combination of 2 VF bin Cs in a 100/110/120V application. The right picture of Figure 15 would result in the same current draw as the left using the same resistor, but this time we are combining 2 Vf B bins and 2 Vf $D$ bins.


Figure 16. Same effect of Vf bin combination

The same idea can be applied for 2 Vf bin Bs in series. These can be replaced with 1 Vf bin A and 1 Vf bin C . If we take a look at the resistor settings, for example a 120 Vac application on page 6(Fig 17), we can see how the math works. The easy calculation is to take the resistor setting for Vf bin A and the resistor setting for Vf bin C, add them together and divide by 2.

If we look at the 2 W configuration:
(1510ohms +1210 ohms) $/ 2=1360$ ohms, which is the same resistor value as Vf bin B.

We can further expand this to other combinations of Vf if we modify Rout for setting the current. This technique can be easily modified for 220/230/240Vac applications. We just add the four resistor values together and divide by 4 since we have 4 LEDs in series.

| Input Voltage | Power <br> dissipation | Target <br> Drive Current | VF bins |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | B | C | D |  |
|  | 2 W |  | $1510 \Omega$ | $1360 \Omega$ | $1210 \Omega$ | $1060 \Omega$ |
|  | 3 W | $25 \mathrm{~mA}, \mathrm{rms}$ | $1125 \Omega$ | $975 \Omega$ | $825 \Omega$ | $675 \Omega$ |
|  | 4 W | $30 \mathrm{~mA}, \mathrm{rms}$ | $870 \Omega$ | $720 \Omega$ | $570 \Omega$ | $420 \Omega$ |

Figure 17. 120Vac resistor settings pulled from page 6

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### 2.7 Color bin selection

Color coordinates of the part AN4240-03 can change over temperature. Color shift can be inimized with a good thermal system design. If color stability is important in a system, it is recommended to design the system based on the specific application temperature. An example of color shift over temperature is shown below in Figure 18. We can see as the board temperature gets hotter we have a color shift to the left. Each application is specific and should be verified in application.


Figure 18. Color coordinate depends on board temperature for AN4240-03

## 3. Protection

### 3.1 Description

AC-LEDs are susceptible to line transients just as DC LEDs which can overheat the components, either causing immediate failure or greatly shortening the useful life of the LEDs. Circuit-protection should be utilized to protect against over-voltage, over-current and over temperature conditions.

### 3.2 Lightning surges, Voltage spikes or Ring Wave Protection

A metal oxide varistor (MOV) is often used to help protect lighting systems from lightning surges and ring-wave effects, and helps manufacturers meet safety and performance standards. The MOV clamps short-duration voltage impulses. Lightning tests according to IEC 61000-4-5 and ring-wave tests according to IEEE C. 62.41 can be used to simulate these real-life threats in the lab.

### 3.3 Over-current and Over-temperature Protection

In both AC-LEDs and DC-LEDs alike, excessive heat at the LED junction can dramatically reduce both the light output and lifespan of the LED.

TE Circuit Protection's PolySwitch polymeric positive temperature coefficient (PPTC) devices help provide over-current and over-temperature protection and can be easily integrated onto a circuit board with the AC-LED. The PPTC acts like a fuse to limit current in a series circuit that drives the LED, yet can automatically reset itself when the fault clears.

An example circuit of a MOV and PPTC is shown in figure 19 below.


Figure 19. Example protection circuit

